

### **Key Features & Benefits**

- RoHS lead-free solder and lead-solder-exempted products are available
- Delivers up to 16 A (88 W)
- Extended input range 9.6 V 14 V
- High efficiency (0.948 at 5 V output)
- Surface-mount package
- Industry-standard footprint and pinout
- Small size and low profile: 1.30" x 0.53" x 0.314" (33.02 x 13.46 x 7.98 mm)
- Weight: 0.23 oz [6.50 g]
- Coplanarity less than 0.003", maximum
- Synchronous Buck Converter topology
- Start-up into pre-biased output
- No minimum load required
- Programmable output voltage via external resistor
- Operating ambient temperature: -40 °C to 85 °C
- Remote output sense
- Remote ON/OFF (positive or negative)
- Fixed-frequency operation
- Auto-reset output overcurrent protection
- Auto-reset overtemperature protection
- High reliability, MTBF approx. 27.2 Million Hours
- calculated per Telcordia TR-332, Method I Case 1
- All materials meet UL94, V-0 flammability rating
- Safety approved to UL/CSA 62368-1 and EN/IEC 62368-1

### YS12S16 DC-DC Converter

9.6 - 14 VDC Input; 0.7525 - 5.5 VDC Programmable @ 16 A

Bel Power Solutions point-of-load converters are recommended for use with regulated bus converters in an Intermediate Bus Architecture (IBA). The YS12S16 non-isolated DC-DC converters deliver up to 16 A of output current in an industry-standard surface-mount package. Operating from a 9.6-14 VDC input, the YS12S16 converters are ideal choices for Intermediate Bus Architectures where point-of-load power delivery is generally a requirement. They provide an extremely tight regulated programmable output voltage of 0.7525 V to 5.5 V.

The YS12S16 converters provide exceptional thermal performance, even in high temperature environments with minimal airflow. This is accomplished through the use of advanced circuitry, packaging, and processing techniques to achieve a design possessing ultra-high efficiency, excellent thermal management and a very low body profile.

The low body profile and the preclusion of heat sinks minimize impedance to system airflow, thus enhancing cooling for both upstream and downstream devices. The use of 100% automation for assembly, coupled with advanced power electronics and thermal design, results in a product with extremely high reliability.

#### **Applications**

- Intermediate Bus Architectures
- Telecommunications
- Data communications
- Distributed Power Architectures
- Servers, workstations

#### **Benefits**

- High efficiency no heat sink required
- Reduces total solution board area
- Tape and reel packing
- Compatible with pick & place equipment
- Minimizes part numbers in inventory
- Low cost



### **Electrical Specifications**

Conditions:  $T_A = 25$  °C, Airflow = 300 LFM (1.5 m/s),  $V_{10} = 12$  VDC,  $V_{10} = 0.7525 - 5.5$  V, unless otherwise specified.

PARAMETER	NOTES	MIN	TYP	MAX	UNITS
Absolute Maximum Ratings					
Input Voltage	Continuous	-0.3		15	VDC
Operating Ambient Temperature		-40		85	°C
Storage Temperature		-55		125	°C
Feature Characteristics					
Switching Frequency			300		kHz
Output Voltage Trim Range <sup>1</sup>	By external resistor, See Trim Table 1	0.7525		5.5	VDC
Remote Sense Compensation <sup>1</sup>	Percent of Vout(NOM)			0.5	VDC
Turn-On Delay Time <sup>2</sup>	Full resistive load				
With Vin = (Converter Enabled, then Vin applied)	From Vin = Vin(min) to Vo=0.1* Vo(nom)		3		ms
With Enable (Vin = Vin(nom) applied, then enabled	From enable to Vo= 0.1*Vo(nom)		3		ms
Rise time <sup>2</sup> (Full resistive load)	From 0.1*Vo(nom) to 0.9*Vo(nom)		4		ms
	Converter Off	-5		0.8	VDC
ON/OFF Control (Positive Logic) <sup>3</sup>	Converter On	2.4		Vin	VDC
	Converter Off	2.4		Vin	VDC
ON/OFF Control (Negative Logic) <sup>3</sup>	Converter On	-5		0.8	VDC
nput Characteristics					
Operating Input Voltage Range		9.6	12	14	VDC
nput Under Voltage Lockout					
Turn-on Threshold			9		VDC
Turn-off Threshold			8.5		VDC
Maximum Input Current	16 ADC Out @ 9.6 VDC In		0.0		,,,,
Maximum input Guiront	V <sub>OUT</sub> = 5.0 VDC			8.9	ADC
	V <sub>OUT</sub> = 3.3 VDC			6	ADC
	V <sub>OUT</sub> = 2.5 VDC			4.6	ADC
	V <sub>OUT</sub> = 2.0 VDC			3.8	ADC
	V <sub>OUT</sub> = 1.8 VDC			3.4	ADC
	V <sub>OUT</sub> = 1.5 VDC			2.9	ADC
	V <sub>OUT</sub> = 1.5 VDC V <sub>OUT</sub> = 1.2 VDC			2.9	ADC
	V <sub>OUT</sub> = 1.0 VDC			2.1	ADC
land 1 Olared In Comment (On a section disability)	V <sub>OUT</sub> = 0.7525 VDC		0	1.7	ADC
Input Stand-by Current (Converter disabled)	V 50.VD0		3		mA
Input No Load Current (Converter enabled)	$V_{OUT} = 5.0 \text{ VDC}$		83		mA
	$V_{OUT} = 3.3 \text{ VDC}$		63		mA
	V <sub>OUT</sub> = 2.5 VDC		53		mA
	V <sub>OUT</sub> = 2.0 VDC		47		mA
	$V_{OUT} = 1.8 \text{ VDC}$		45		mA
	$V_{OUT} = 1.5 \text{ VDC}$		43		mA
	V <sub>OUT</sub> = 1.2 VDC		41		mA
	$V_{OUT} = 1.0 \text{ VDC}$		39		mA
	$V_{OUT} = 0.7525 \text{ VDC}$		35		mA
Input Reflected-Ripple Current - is	See Fig. E for setup. (BW = 20 MHz)				
	$V_{OUT} = 5.0 \text{ VDC}$		60		$mA_{P-P}$
	$V_{OUT} = 3.3 \text{ VDC}$		43		$mA_{P-P}$
	V <sub>OUT</sub> = 2.5 VDC		35		mA <sub>P-P</sub>
	V <sub>OUT</sub> = 2.0 VDC		35		$mA_{P-P}$
	V <sub>OUT</sub> = 1.8 VDC		35		$mA_{P-P}$
	$V_{OUT} = 1.5 \text{ VDC}$		33		$mA_{P-P}$



$V_{Out} = 1.0 \text{ VDC} \qquad 21 \qquad mA_{P} \\ V_{Out} = 0.7525 \text{ VDC} \qquad 19 \qquad mA_{P} \\ Input Voltage Ripple Rejection \qquad 120 \text{ Hz} \qquad 72 \qquad dB \\ \textbf{Output Characteristics} \\ \textbf{Output Characteristics} \\ \textbf{Output Pegulation} \\ \textbf{Over Line} \qquad Full resistive load \qquad 0.5 \qquad mV \\ \textbf{Over Load} \qquad From no load to full load \qquad 5 \qquad mV \\ \textbf{Over Load} \qquad From no load to full load \qquad 5 \qquad mV \\ \textbf{Over Load} \qquad From no load to full load \qquad 5 \qquad mV \\ \textbf{Over load} \qquad From no load to full load \qquad 5 \qquad mV \\ \textbf{Output Voltage Range} \qquad -2.5 \qquad +2.5 \qquad \%Vou \\ \textbf{Over all operating input voltage, resistive load and temperature (Fig. E) Peak-to-Peak \qquad Vour = 0.7525 \text{ VDC} \qquad 12 \qquad 19 \qquad mV_{P-1} \\ \textbf{Peak-to-Peak} \qquad Vour = 0.7525 \text{ VDC} \qquad 12 \qquad 19 \qquad mV_{P-1} \\ \textbf{External Load Capacitance} \qquad Plus full load (resistive) \\ \textbf{Min ESR} > 10 \text{ mΩ} \qquad 5,000 \qquad \muF \\ \textbf{Min ESR} > 10 \text{ mΩ} \qquad 5,000 \qquad \muF \\ \textbf{Output Current Range} \qquad 0 \qquad 16 \qquad A \\ \textbf{Output Current Limit Inception (lour)} \qquad 25 \qquad A \\ \textbf{Output Short- Circuit Current , RMS Value} \qquad Short=10 \text{ mΩ, continuous} \qquad 4 \qquad A \\ \textbf{Opnamic Response} \qquad 45 \qquad \mus \\ \textbf{Unloading current change from 8A - 16A, di/dt = 5 A/μS} \qquad Co = 100  \muF  ceramic + 470  \muF  POS \qquad 140 \qquad mV \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{Settling Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ \textbf{More Time Time (Vour < 10% peak deviation)} \qquad 45 \qquad \mus \\ More Time Time Time Time Time Time Time Tim$						
Vour = 0.7525 VDC   19   mAe   mout Voltage Ripple Rejection   120 Hz   72   dB   Mae		V <sub>OUT</sub> = 1.2 VDC		23		mA <sub>P-F</sub>
Table   Voltage   Ripple   Rejection   120 Hz   72   dB   Dutput Characteristics   Voltage   Set Point (no load)   -1.5   Vout   +1.5   % Vout   Voltage   Set Point (no load)   From no load to full load   5   mV   Over Load   Prom no load to full load   5   mV   Over Load   Prom no load to full load   5   mV   Voltage   Range   Vour   4.2.5   % Vout and temperature conditions until end of life   Vour = 0.7525 VDC   12   19   mVρ.   Peak-to-Peak   Vour = 0.7525 VDC   12   19   mVρ.   Peak-to-Peak   Vour = 5.0 VDC   40   65   65   65   65   65   65   65   6		V <sub>OUT</sub> = 1.0 VDC		21		$mA_{P-F}$
Output Characteristics           Dutput Voltage Set Point (no load)         -1.5         Vout         +1.5         %Voit           Dutput Regulation         -2.5         -2.5         mV           Over Line         Full resistive load         .5         mV           Over Load         From no load to full load         5         mV           Output Voltage Range         -2.5         +2.5         %Voit           Over all operating input voltage, resistive load and temperature (Fig. E)         -2.5         +2.5         %Voit           Output Ripple and Noise - 20MHz bandwidth         Over line, load and temperature (Fig. E)         -2.5         +2.5         %Voit           Peak-to-Peak         Vour = 0.7525 VDC         40         65         mV-L           External Load Capacitance         Plus full load (resistive)		$V_{\text{OUT}} = 0.7525 \text{ VDC}$		19		$mA_{P-}$
Dutput Voltage Set Point (no load)         -1.5         Vout         +1.5         %Voto           Dutput Regulation         Pull resistive load         0.5         mV           Over Load         From no load to full load         5.5         mV           Dutput Voltage Range         2.5         +2.5         **Voto           Over all operating input voltage, resistive load and temperature conditions until end of life)         Over line, load and temperature (Fig. E)         12         19         mVp-           Dutput Ripple and Noise - 20MHz bandwidth         Over line, load and temperature (Fig. E)         12         19         mVp-           Peak-to-Peak         Vour = 0.7525 VDC         12         19         mVp-           External Load Capacitance         Plus full load (resistive)         1         1,000         μF           Min ESR > 1mΩ         1,000         μF         1,000         μF           Output Current Range         0         16         A           Output Current Range         Short=10 mΩ, continuous         4         A           Output Short- Circuit Current , RMS Value         Short=10 mΩ, continuous         4         A           Dulloading current change from 8A – 16A, di/dt = 5 A/μS         Co = 100 μF ceramic + 470 μF POS         140         mV <tr< td=""><td>Input Voltage Ripple Rejection</td><td>120 Hz</td><td></td><td>72</td><td></td><td>dB</td></tr<>	Input Voltage Ripple Rejection	120 Hz		72		dB
Coutput Regulation         Full resistive load         0.5         mV           Over Load         From no load to full load         5         mV           Output Voltage Range         -2.5         +2.5         %Vou           Over all operating input voltage, resistive load         -2.5         +2.5         %Vou           Output Ripple and Noise - 20MHz bandwidth         Over line, load and temperature (Fig. E)         12         19         mV <sub>P-I</sub> Peak-to-Peak         Vour = 0.7525 VDC         12         19         mV <sub>P-I</sub> External Load Capacitance         Plus full load (resistive)         40         65         mV <sub>P-I</sub> External Load Capacitance         Plus full load (resistive)         1,000         μF           Min ESR > ImΩ         1,000         μF           Min ESR > ImΩ         1,000         μF           Output Current Range         0         16         A           Output Current Limit Inception (lour)         25         A           Output Current Limit Inception (lour)         25         A           Output Current Change from 8A – 16A, di/dt = 5 A/μS         Co = 100 μF ceramic + 470 μF POS         140         mV           Dulloading current change from 16A – 8A, di/dt = -5 A/μS         Co = 100 μF ceramic + 470 μF POS	Output Characteristics					
Over Line         Full resistive load         0.5         mV           Over Load         From no load to full load         5         mV           Output Voltage Range         -2.5         +2.5         %Vorall operating input voltage, resistive load and temperature conditions until end of life )         -2.5         +2.5         %Vorall operating input voltage, resistive load and temperature (Fig. E)           Output Ripple and Noise - 20MHz bandwidth         Over line, load and temperature (Fig. E)         12         19         mVp.           Peak-to-Peak         Vour = 0.7525 VDC         40         65         mVp.           Peak-to-Peak         Vour = 5.0 VDC         40         65         mVp.           External Load Capacitance         Plus full load (resistive)         1,000         μF           Min ESR > 1mΩ         1,000         μF           Min ESR > 1mΩ         5,000         μF           Min ESR > 1mΩ         5,000         μF           Output Current Range         8nort=10 mΩ, continuous         4         A           Output Short- Circuit Current , RMS Value         Short=10 mΩ, continuous         4         A           Output Short- Circuit Current , RMS Value         Short=10 mΩ, continuous         45         μs           Unidading current change from 8A – 16A, di/dt = 5 A/μS<	Output Voltage Set Point (no load)		-1.5	Vout	+1.5	%Vou
Over Load         From no load to full load         5         mV           Output Voltage Range         -2.5         +2.5         %Vol           Over all operating input voltage, resistive load and temperature conditions until end of life)         -2.5         +2.5         %Vou           Output Ripple and Noise - 20MHz bandwidth         Over line, load and temperature (Fig. E)         12         19         mVp-           Peak-to-Peak         Vour = 5.0 VDC         40         65         mVp-           External Load Capacitance         Plus full load (resistive)         1,000         μF           Min ESR > 1 mΩ         5,000         μF           Output Current Range         0         16         A           Output Uterent Limit Inception (lour)         25         A           Output Short- Circuit Current , RMS Value         Short=10 mΩ, continuous         4         A           Output Short- Circuit Current , RMS Value         Short=10 mΩ, continuous         4         A           Output Scittling Time (Vour < 10% peak deviation)	Output Regulation					
Output Voltage Range         -2.5         +2.5         %Voltage Range           Over all operating input voltage, resistive load and temperature conditions until end of life )         -2.5         +2.5         %Voltage Range           Output Ripple and Noise - 20MHz bandwidth         Over line, load and temperature (Fig. E)	Over Line	Full resistive load		0.5		mV
Over all operating input voltage, resistive load and temperature conditions until end of life	Over Load	From no load to full load		5		mV
Peak-to-Peak   Vour = 0.7525 VDC   12   19   mV <sub>P-I</sub>     Peak-to-Peak   Vour = 5.0 VDC   40   65   mV <sub>P-I</sub>     External Load Capacitance   Plus full load (resistive)     Min ESR > 1 mΩ   1,000   μF     Min ESR > 10 mΩ   5,000   μF     Output Current Range   0   16   A     Output Current Limit Inception (lour)   25   A     Output Current Limit Inception (lour)   25   A     Output Short- Circuit Current , RMS Value   Short=10 mΩ, continuous   4   A     Output Short- Circuit Current , RMS Value   Short=10 mΩ, continuous   45   μs     Output Short- Circuit Current , RMS Value   Short=10 mΩ, continuous   45   μs     Output Short- Circuit Current , RMS Value   Short=10 mΩ, continuous   45   μs     Output Short- Circuit Current , RMS Value   Short=10 mΩ, continuous   45   μs     Output Short- Circuit Current , RMS Value   Short=10 mΩ, continuous   45   μs     Output Short- Circuit Current , RMS Value   Short=10 mΩ, continuous   45   μs     Output Short- Circuit Current , RMS Value   Short=10 mΩ, continuous   45   μs     Output Current change from 8A – 16A, di/dt = 5 A/μS   Co = 100 μF ceramic + 470 μF POS   140   mV     Settling Time (Vour < 10% peak deviation)   45   μs     Efficiency   Full load (16A)   Full load (16A)   Vour = 5.0 VDC   94.8   %   %     Vour = 2.0 VDC   99.5   %   %     Vour = 2.5 VDC   99.5   %   %     Vour = 1.8 VDC   88.0   %   %   %     Vour = 1.5 VDC   86.0   %   %   %     Vour = 1.5 VDC   84.0   %   %   %   %   %   %   %   %   %	Output Voltage Range (Over all operating input voltage, resistive load and temperature conditions until end of life)		-2.5		+2.5	%Vou
Peak-to-Peak   Vour = 5.0 VDC   40 65 mVP-Fexternal Load Capacitance   Plus full load (resistive)   1,000 μF Min ESR > 1mΩ   1,000 μF Min ESR > 10 mΩ   5,000 μF Output Current Range   0 16 A Output Current Limit Inception (lour)   25 A Output Current Current Current PMS Value   Short=10 mΩ, continuous   4 A A Output Current Change from 8A – 16A, di/dt = 5 A/μS   Co = 100μF ceramic + 470 μF POS   140 mV Settling Time (Vour < 10% peak deviation)   45 μs Unloading current change from 16A – 8A, di/dt = -5 A/μS   Co = 100 μF ceramic + 470 μF POS   140 mV Settling Time (Vour < 10% peak deviation)   45 μs Efficiency   Full load (16A)   45 μs Efficiency   50 VDC   94.8   % Vour = 3.3 VDC   92.5   % Vour = 3.3 VDC   92.5   % Vour = 2.0 VDC   89.0   % Vour = 2.0 VDC   89.0   % Vour = 1.8 VDC   88.0   % Vour = 1.8 VDC   88.0   % Vour = 1.8 VDC   86.0   % Vour = 1.2 VDC   86.0   % Vour = 1.2 VDC   84.0   % Vour = 1.2 VDC   84.0   % Vour = 1.2 VDC   84.0   % Vour = 1.2 VDC   86.0   % Vour = 1.2 VDC   86.0   % Vour = 1.0 VDC   80.5   % Vour = 1.0 V	Output Ripple and Noise - 20MHz bandwidth	Over line, load and temperature (Fig. E)				
External Load Capacitance Plus full load (resistive)  Min ESR > 1mΩ 1,000 μF  Min ESR > 10 mΩ 5,000 μF  Output Current Range 0 16 A  Output Current Limit Inception (Iour) 25 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A  Output Short- 10 mΩ, continuous 10 mµ  Output Short- 10 mΩ  Output Short- 10 mΩ  Output Short- 10 mΩ  Outpu	Peak-to-Peak	$V_{OUT} = 0.7525 \text{ VDC}$		12	19	$mV_{P-P}$
Min ESR > 1mΩ	Peak-to-Peak	$V_{OUT} = 5.0 \text{ VDC}$		40	65	$mV_{P-F}$
Min ESR > 10 mΩ 5,000 μF Cutput Current Range 0 16 A Cutput Current Limit Inception (lour) 25 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Circuit Current , RMS Value Short=10 mΩ, continuous 4 A Cutput Short- Short Short- Shor	External Load Capacitance	Plus full load (resistive)				
Output Current Range         0         16         A           Output Current Limit Inception (lour)         25         A           Output Short- Circuit Current , RMS Value         Short=10 mΩ, continuous         4         A           Opynamic Response         Value	Min ESR $> 1m\Omega$				1,000	μF
Output Current Limit Inception (Iour)       25       A         Output Short- Circuit Current , RMS Value       Short=10 mΩ, continuous       4       A         Dynamic Response         Load current change from 8A – 16A, di/dt = 5 A/μS       Co = $100 \mu F$ ceramic + $470 \mu F$ POS       140       mV         Settling Time (Vour < 10% peak deviation)       45       μs         Unloading current change from $16A - 8A$ , di/dt = $-5 A/\mu S$ Co = $100 \mu F$ ceramic + $470 \mu F$ POS       140       mV         Settling Time (Vour < $10\%$ peak deviation)       Full load ( $16A$ )       45       μs         Efficiency         Full load ( $16A$ )       Vour = $5.0 \text{ VDC}$ 94.8       %         Vour = $3.3 \text{ VDC}$ 92.5       %         Vour = $2.5 \text{ VDC}$ 90.5       %         Vour = $2.0 \text{ VDC}$ 89.0       %         Vour = $1.8 \text{ VDC}$ 88.0       %         Vour = $1.5 \text{ VDC}$ 86.0       %         Vour = $1.2 \text{ VDC}$ 84.0       %         Vour = $1.0 \text{ VDC}$ 80.5       %	Min ESR $> 10 \text{ m}\Omega$				5,000	μF
Dutput Short- Circuit Current , RMS Value       Short=10 mΩ, continuous       4       A         Dynamic Response         Load current change from 8A – 16A, di/dt = 5 A/μS       Co = 100μF ceramic + 470 μF POS       140       mV         Settling Time (Vouт < 10% peak deviation)	Output Current Range		0		16	Α
Dynamic Response           Load current change from 8A – 16A, di/dt = 5 A/μS         Co = 100μF ceramic + 470 μF POS         140         mV           Settling Time (V <sub>OUT</sub> < 10% peak deviation)	Output Current Limit Inception (Iout)			25		Α
Load current change from 8A – 16A, di/dt = 5 A/μS	Output Short- Circuit Current , RMS Value	Short=10 mΩ, continuous		4		Α
Settling Time ( $V_{OUT} < 10\%$ peak deviation) 45 µs Unloading current change from 16A – 8A, di/dt = -5 A/ $\mu$ S Co = 100 $\mu$ F ceramic + 470 $\mu$ F POS 140 mV Settling Time ( $V_{OUT} < 10\%$ peak deviation) 45 µs Efficiency Full load (16A) $V_{OUT} = 5.0 \text{ VDC} \qquad 94.8 \qquad \% \\ V_{OUT} = 3.3 \text{ VDC} \qquad 92.5 \qquad \% \\ V_{OUT} = 2.5 \text{ VDC} \qquad 90.5 \qquad \% \\ V_{OUT} = 2.0 \text{ VDC} \qquad 89.0 \qquad \% \\ V_{OUT} = 1.8 \text{ VDC} \qquad 88.0 \qquad \% \\ V_{OUT} = 1.5 \text{ VDC} \qquad 86.0 \qquad \% \\ V_{OUT} = 1.2 \text{ VDC} \qquad 84.0 \qquad \% \\ V_{OUT} = 1.0 \text{ VDC} \qquad 80.5 \qquad \% \\$	Dynamic Response					
Unloading current change from 16A – 8A, di/dt = -5 A/ $\mu$ S	Load current change from 8A – 16A, di/dt = 5 A/μS	Co = $100\mu$ F ceramic + 470 $\mu$ F POS		140		mV
Settling Time (Vouт < 10% peak deviation)       45       μs         Efficiency       Full load (16A)       94.8       %         Vouт = 5.0 VDC       94.8       %         VouT = 3.3 VDC       92.5       %         VouT = 2.5 VDC       90.5       %         VouT = 2.0 VDC       89.0       %         VouT = 1.8 VDC       88.0       %         VouT = 1.5 VDC       86.0       %         VouT = 1.2 VDC       84.0       %         VouT = 1.0 VDC       80.5       %	Settling Time (V <sub>OUT</sub> < 10% peak deviation)			45		μs
Efficiency         Full load (16A)           Vout = 5.0 VDC         94.8         %           Vout = 3.3 VDC         92.5         %           Vout = 2.5 VDC         90.5         %           Vout = 2.0 VDC         89.0         %           Vout = 1.8 VDC         88.0         %           Vout = 1.5 VDC         86.0         %           Vout = 1.2 VDC         84.0         %           Vout = 1.0 VDC         80.5         %	Unloading current change from $16A - 8A$ , $di/dt = -5 A/\mu S$	Co = 100 $\mu$ F ceramic + 470 $\mu$ F POS		140		mV
VOUT = 5.0 VDC       94.8       %         VOUT = 3.3 VDC       92.5       %         VOUT = 2.5 VDC       90.5       %         VOUT = 2.0 VDC       89.0       %         VOUT = 1.8 VDC       88.0       %         VOUT = 1.5 VDC       86.0       %         VOUT = 1.2 VDC       84.0       %         VOUT = 1.0 VDC       80.5       %	Settling Time (Vout < 10% peak deviation)			45		μs
VOUT = 3.3 VDC       92.5       %         VOUT = 2.5 VDC       90.5       %         VOUT = 2.0 VDC       89.0       %         VOUT = 1.8 VDC       88.0       %         VOUT = 1.5 VDC       86.0       %         VOUT = 1.2 VDC       84.0       %         VOUT = 1.0 VDC       80.5       %	Efficiency	Full load (16A)				
Vout = 2.5 VDC       90.5       %         Vout = 2.0 VDC       89.0       %         Vout = 1.8 VDC       88.0       %         Vout = 1.5 VDC       86.0       %         Vout = 1.2 VDC       84.0       %         Vout = 1.0 VDC       80.5       %		$V_{OUT} = 5.0 \text{ VDC}$		94.8		%
VOUT = 2.0 VDC       89.0       %         VOUT = 1.8 VDC       88.0       %         VOUT = 1.5 VDC       86.0       %         VOUT = 1.2 VDC       84.0       %         VOUT = 1.0 VDC       80.5       %		$V_{OUT} = 3.3 \text{ VDC}$		92.5		%
VOUT = 1.8 VDC       88.0       %         VOUT = 1.5 VDC       86.0       %         VOUT = 1.2 VDC       84.0       %         VOUT = 1.0 VDC       80.5       %		$V_{OUT} = 2.5 \text{ VDC}$		90.5		%
Vout = 1.5 VDC       86.0       %         Vout = 1.2 VDC       84.0       %         Vout = 1.0 VDC       80.5       %		$V_{OUT} = 2.0 \text{ VDC}$		89.0		%
VOUT = 1.2 VDC       84.0       %         VOUT = 1.0 VDC       80.5       %		$V_{OUT} = 1.8 \text{ VDC}$		88.0		%
V <sub>OUT</sub> = 1.0 VDC 80.5 %		$V_{OUT} = 1.5 \text{ VDC}$		86.0		%
		V <sub>OUT</sub> = 1.2 VDC		84.0		%
$V_{OUT} = 0.7525 \text{ VDC}$ 77.0 %		$V_{OUT} = 1.0 \text{ VDC}$		80.5		%
		$V_{OUT} = 0.7525 \text{ VDC}$		77.0		%

#### Notes:

- The output voltage should not exceed 5.5V (taking into account both the programming and remote sense compensation).
- Note that start-up time is the sum of turn-on delay time and rise time.
- <sup>3</sup> The converter is on if ON/OFF pin is left open.



### **Operations**

#### **Input and Output Impedance**

The YS12S16 converter should be connected via a low impedance to the DC power source. In many applications, the inductance associated with the distribution from the power source to the input of the converter can affect the stability of the converter. It is recommended to use decoupling capacitors (minimum 47  $\mu$ F) placed as close as possible to the converter input pins in order to ensure stability of the converter and reduce input ripple voltage. Internally, the converter has 30  $\mu$ F (low ESR ceramics) of input capacitance.

In a typical application, low - ESR tantalum or POS capacitors will be sufficient to provide adequate ripple voltage filtering at the input of the converter. However, very low ESR ceramic capacitors 47  $\mu$ F-100  $\mu$ F are recommended at the input of the converter in order to minimize the input ripple voltage. They should be placed as close as possible to the input pins of the converter.

The YS12S16 has been designed for stable operation with or without external capacitance. Low ESR ceramic capacitors placed as close as possible to the load (minimum 47  $\mu$ F) are recommended for improved transient performance and lower output voltage ripple.

It is important to keep low resistance and low inductance PCB traces for connecting load to the output pins of the converter in order to maintain good load regulation.

### ON/OFF (Pin 1)

The ON/OFF pin is used to turn the power converter on or off remotely via a system signal. There are two remote control options available, positive logic (standard option) and negative logic, and both are referenced to GND. The typical connections are shown in Fig. A.

The positive logic version turns the converter on when the ON/OFF pin is at a logic high or left open, and turns the converter off when at a logic low or shorted to GND.

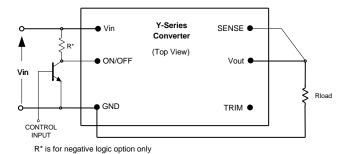


Fig. A: Circuit configuration for ON/OFF function.

The negative logic version turns the converter on when the ON/OFF pin is at logic low or left open, and turns the converter off when the ON/OFF pin is at a logic high or connected to Vin.

The ON/OFF pin is internally pulled-up to Vin for a positive logic version, and pulled-down for a negative logic version. A TTL or CMOS logic gate, open collector (open drain) transistor can be used to drive the ON/OFF pin. When using open collector (open drain) transistor with a negative logic option, add a pull-up resistor (R\*) of 75K to Vin as shown in Fig. A;

This device must be capable of:

- sinking up to 0.2 mA at a low level voltage of ≤ 0.8 V
- sourcing up to 0.25 mA at a high logic level of 2.3 V 5 V
- sourcing up to 0.75 mA when connected to Vin.

### Remote Sense (Pin 2)

The remote sense feature of the converter compensates for voltage drops occurring only between Vout pin (Pin 4) of the converter and the load. The SENSE (Pin 2) pin should be connected at the load or at the point where regulation is required (see Fig. B). There is no sense feature on the output GND return pin, where the solid ground plane should provide low voltage drop.



If remote sensing is not required, the SENSE pin must be connected to the Vout pin (Pin 4) to ensure the converter will regulate at the specified output voltage. If these connections are not made, the converter will deliver an output voltage that is slightly higher than the specified value.

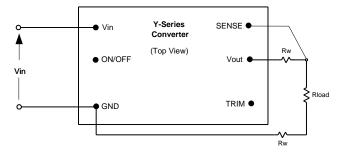


Fig. B: Remote sense circuit configuration.

Because the sense lead carries minimal current, large trace on the end-user board are not required. However, sense trace should be located close to a ground plane to minimize system noise and insure optimum performance. When utilizing the remote sense feature, care must be taken not to exceed the maximum allowable output power capability of the converter, equal to the product of the nominal output voltage and the allowable output current for the given conditions.

When using remote sense, the output voltage at the converter can be increased up to 0.5 V above the nominal rating in order to maintain the required voltage across the load. Therefore, the designer must, if necessary, decrease the maximum current (originally obtained from the derating curves) by the same percentage to ensure the converter's actual output power remains at or below the maximum allowable output power.

#### **Output Voltage Programming (Pin 3)**

The output voltage can be programmed from

0.7525 V to 5.5 V by connecting an external resistor between TRIM pin (Pin 3) and GND pin (Pin 5); see Fig. C. A trim resistor, RTRIM, for a desired output voltage can be calculated using the following equation:

R<sub>TRIM</sub> = 
$$\frac{10.5}{\text{(Vo-REQ - 0.7525)}}$$
 - 1 [kΩ]

where.

**R**TRIM = Required value of trim resistor  $[k\Omega]$ 

**Vo-REQ** = Desired (trimmed) output voltage [V]

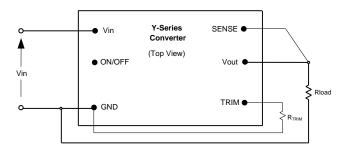


Fig. C: Configuration for programming output voltage.

Note that the tolerance of a trim resistor directly affects the output voltage tolerance. It is recommended to use standard 1% or 0.5% resistors; for tighter tolerance, two resistors in parallel are recommended rather than one standard value from Table 1.

Ground pin of the trim resistor should be connected directly to the converter GND pin (Pin 5) with no voltage drop in between. Table 1 provides the trim resistor values for popular output voltages.



Table 1: Trim Resistor Value

V <sub>0-REG</sub> [V]	R <sub>TRIM</sub> [kΩ]	The Closest Standard Value [kΩ]
0.7525	open	
1.0	41.42	41.2
1.2	22.46	22.6
1.5	13.05	13.0
1.8	9.02	9.09
2.0	7.42	7.50
2.5	5.01	4.99
3.3	3.12	3.09
5.0	1.47	1.47
5.5	1.21	1.21

The output voltage can be also programmed by external voltage source. To make trimming less sensitive, a series external resistor Rext is recommended between TRIM pin and programming voltage source. Control Voltage can be calculated by the formula:

$$V_{\text{CTRL}} = 0.7 - \frac{(1 + R_{\text{EXT}})(V_{\text{O-REQ}} - 0.7525)}{15}$$
 [V]

where,

VCTRL = Control voltage [V]

 $\mathbf{R}_{\text{EXT}}$  = External resistor between TRIM pin and voltage source; the value can be chosen depending on the required output voltage range [k $\Omega$ ].

Control voltages with  $\mathbf{R}\mathbf{E}\mathbf{x}\mathbf{T}=0$  and  $\mathbf{R}\mathbf{E}\mathbf{x}\mathbf{T}=15K$  are shown in Table 2.

Table 2: Control Voltage [VDC]

V <sub>0-REG</sub> [V]	V <sub>CTRL</sub> (R <sub>EXT</sub> = 0)	V <sub>CTRL</sub> (R <sub>EXT</sub> = 15K)
0.7525	0.700	0.700
1.0	0.684	0.436
1.2	0.670	0.223
1.5	0.650	-0.097
1.8	0.630	-0.417
2.0	0.617	-0.631
2.5	0.584	-1.164
3.3	0.530	-2.017
5.0	0.417	-3.831
5.5	0.384	-4.364

### **Protection Features**

### **Input Undervoltage Lockout**

Input undervoltage lockout is standard with this converter. The converter will shut down when the input voltage drops below a pre-determined voltage; it will start automatically when Vin returns to a specified range.

The input voltage must be at least 9.6V (typically 9V) for the converter to turn on. Once the converter has been turned on, it will shut off when the input voltage drops below typically 8.5V.

#### **Output Overcurrent Protection (OCP)**

The converter is protected against overcurrent and short circuit conditions. Upon sensing an over-current condition, the converter will enter hiccup mode. Once over-load or short circuit condition is removed, Vout will return to nominal value.



#### **Overtemperature Protection (OTP)**

The converter will shut down under an over-temperature condition to protect itself from overheating caused by operation outside the thermal derating curves, or operation in abnormal conditions such as system fan failure. After the converter has cooled to a safe operating temperature, it will automatically restart.

### **Safety Requirements**

The converter meets North American and International safety regulatory requirements per UL/CSA 62368-1 and EN/IEC 62368-1. The maximum DC voltage between any two pins is Vin under all operating conditions. Therefore, the unit has ELV (extra low voltage) output; it meets ES1 requirements under the condition that all input voltages are ELV. The converter is not internally fused. To comply with safety agencies requirements, a recognized fuse with a maximum rating of 15 Amps must be used in series with the input line.

#### Characterization

#### **General Information**

The converter has been characterized for many operational aspects, to include thermal derating (maximum load current as a function of ambient temperature and airflow) for vertical mounting, efficiency, start-up and shutdown parameters, output ripple and noise, transient response to load step-change, overload and short circuit. The figures are numbered as Fig. x.y, where x indicates the different output voltages, and y associates with specific plots (y = 1 for the vertical thermal derating, ...). For example, Fig. x.1 will refer to the vertical thermal derating for all the output voltages in general.

The following pages contain specific plots or waveforms associated with the converter. Additional comments for specific data are provided below.

#### **Test Conditions**

All data presented were taken with the converter soldered to a test board, specifically a 0.060" thick printed wiring board (PWB) with four layers. The top and bottom layers were not metalized. The two inner layers, comprising two-ounce copper, were used to provide traces for connectivity to the converter.

The lack of metalization on the outer layers as well as the limited thermal connection ensured that heat transfer from the converter to the PWB was minimized. This provides a worst-case but consistent scenario for thermal derating purposes.

All measurements requiring airflow were made in the vertical and horizontal wind tunnel facilities using Infrared (IR) thermography and thermocouples for thermometry.

Ensuring components on the converter do not exceed their ratings is important to maintaining high reliability. If one anticipates operating the converter at or close to the maximum loads specified in the derating curves, it is prudent to check actual operating temperatures in the application. Thermographic imaging is preferable; if this capability is not available, then thermocouples may be used. . It is recommended the use of AWG #40 gauge thermocouples to ensure measurement accuracy. Careful routing of the thermocouple leads will further minimize measurement error. Refer to Fig. D for optimum measuring thermocouple locations.

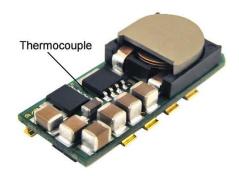


Fig. D: Location of the thermocouple for thermal testing.





#### **Thermal Derating**

Load current vs. ambient temperature and airflow rates are given in Figs. x.1 for maximum temperature of 120 °C. Ambient temperature was varied between 25 °C and 85 °C, with airflow rates from 30 to 500 LFM (0.15 m/s to 2.5 m/s), and vertical converter mounting. The airflow during the testing is parallel to the short axis of the converter, going from pin 1 and pin 6 to pins 2 – 5.

For each set of conditions, the maximum load current is defined as the lowest of:

- (i) The output current at which any MOSFET temperature does not exceed a maximum specified temperature (120 °C) as indicated by the thermo-graphic image, or
- (ii) The maximum current rating of the converter (16 A)

During normal operation, derating curves with maximum FET temperature less than or equal to 120 °C should not be exceeded. Temperature on the PCB at the thermocouple location shown in Fig. D should not exceed 120 °C in order to operate inside the derating curves.

#### **Efficiency**

Figure x.2 shows the efficiency vs. load current plot for ambient temperature of 25 °C, airflow rate of 200 LFM (1 m/s) and input voltages of 9.6 V, 12 V, and 14 V.

#### **Power Dissipation**

Fig. x.3 shows the power dissipation vs. load current plot for Ta = 25 °C, airflow rate of 200 LFM (1 m/s) with vertical mounting and input voltages of 9.6 V, 12 V, and 14 V.

#### **Ripple and Noise**

The output voltage ripple waveform is measured at full rated load current. Note that all output voltage waveforms are measured across a 1  $\mu$ F ceramic capacitor.

The output voltage ripple and input reflected ripple current waveforms are obtained using the test setup shown in Figure E.

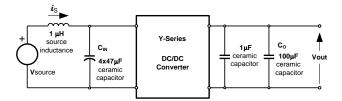


Fig. E: Test setup for measuring input reflected ripple currents, i₅ and output voltage ripple.



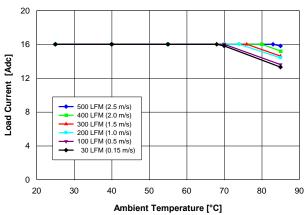


Fig. 5.0V.1: Available load current vs. ambient temperature and airflow rates for Vout = 5.0V converter mounted vertically with Vin = 12V, and maximum MOSFET temperature ≤ 120°C.

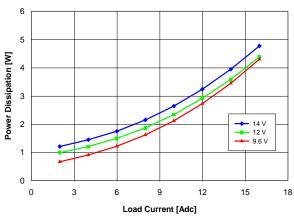


Fig. 5.0V.3: Power loss vs. load current and input voltage for Vout = 5.0V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

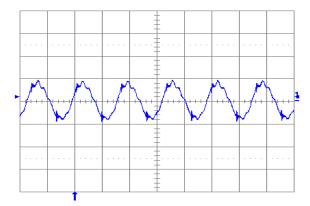


Fig. 5.0V.5: Output voltage ripple (20mV/div.) at full rated load current into a resistive load with external capacitance 100μF ceramic + 1μF ceramic and Vin = 12V for Vout = 5.0V.

Time scale: 2μs/div.

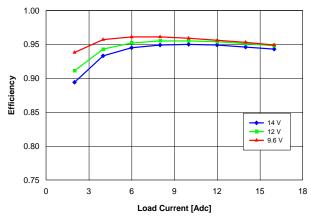


Fig. 5.0V.2: Efficiency vs. load current and input voltage for Vout = 5.0V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

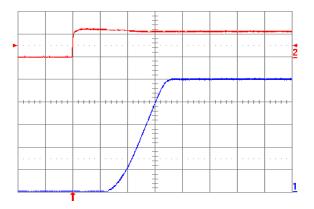


Fig. 5.0V.4: Turn-on transient for Vout = 5.0V with application of Vin at full rated load current (resistive) and 100μF external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale: 2ms/div.

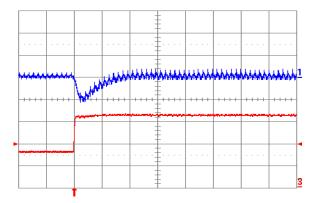


Fig. 5.0V.6: Output voltage response for Vout = 5.0V to positive load current step change from 8A to 16A with slew rate of 5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.



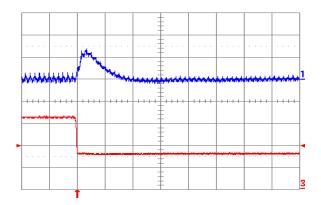


Fig. 5.0V.7: Output voltage response for Vout = 5.0V to negative load current step change from 16A to 8A with slew rate of -5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

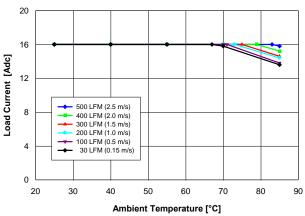


Fig. 3.3V.1: Available load current vs. ambient temperature and airflow rates for Vout = 3.3V converter mounted vertically with Vin = 12V, and maximum MOSFET temperature ≤ 120°C.

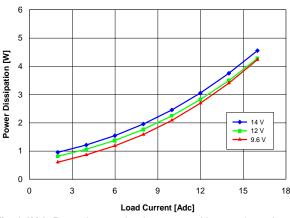


Fig. 3.3V.3: Power loss vs. load current and input voltage for Vout = 3.3V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

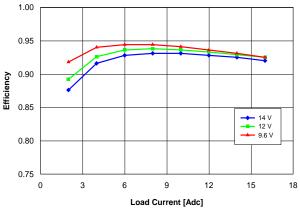


Fig. 3.3V.2: Efficiency vs. load current and input voltage for Vout = 3.3V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

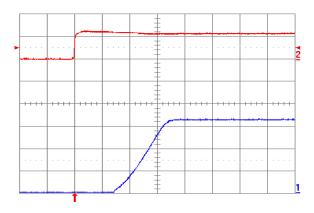


Fig. 3.3V.4: Turn-on transient for Vout = 3.3V with application of Vin at full rated load current (resistive) and 100μF external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale: 2ms/div.



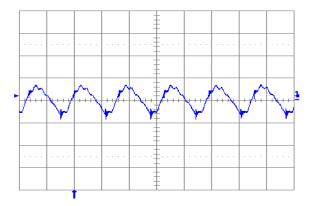


Fig. 3.3V.5: Output voltage ripple (20mV/div.) at full rated load current into a resistive load with external capacitance 100μF ceramic + 1μF ceramic and Vin = 12V for Vout = 3.3V.

Time scale: 2μs/div.

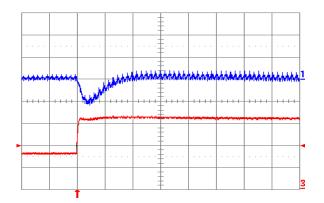


Fig. 3.3V.6: Output voltage response for Vout = 3.3V to positive load current step change from 8A to 16A with slew rate of 5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

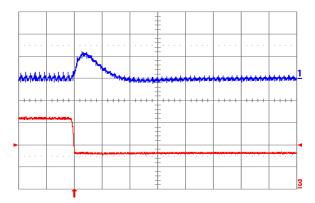


Fig. 3.3V.7: Output voltage response for Vout = 3.3V to negative load current step change from 16A to 8A with slew rate of -5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

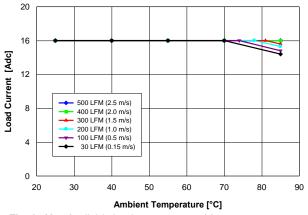


Fig. 2.5V.1: Available load current vs. ambient temperature and airflow rates for Vout = 2.5V converter mounted vertically with Vin = 12V, and maximum MOSFET temperature ≤ 120°C.

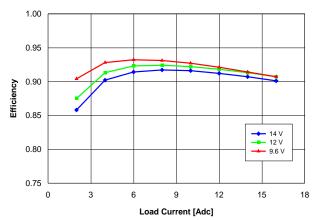


Fig. 2.5V.2: Efficiency vs. load current and input voltage for Vout = 2.5V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.



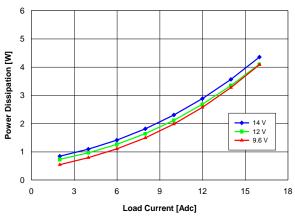


Fig. 2.5V.3: Power loss vs. load current and input voltage for Vout = 2.5V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

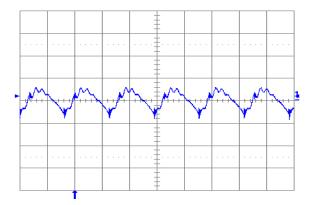


Fig. 2.5V.5: Output voltage ripple (20mV/div.) at full rated load current into a resistive load with external capacitance 100μF ceramic + 1μF ceramic and Vin = 12V for Vout = 2.5V.

Time scale: 2μs/div.

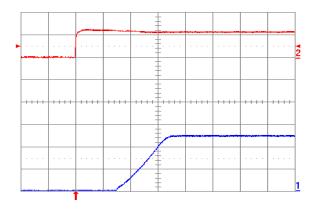


Fig. 2.5V.4: Turn-on transient for Vout = 2.5V with application of Vin at full rated load current (resistive) and 100μF external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale: 2ms/div.

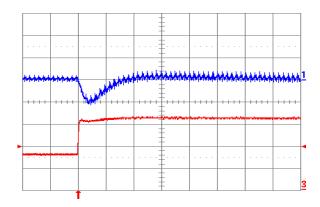


Fig. 2.5V.6: Output voltage response for Vout = 2.5V to positive load current step change from 8A to 16A with slew rate of 5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

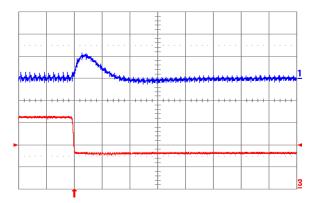


Fig. 2.5V.7: Output voltage response for Vout = 2.5V to negative load current step change from 16A to 8A with slew rate of -5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.





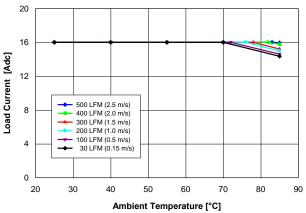


Fig. 2.0V.1: Available load current vs. ambient temperature and airflow rates for Vout = 2.0V converter mounted vertically with Vin = 12V, and maximum MOSFET temperature ≤ 120°C.

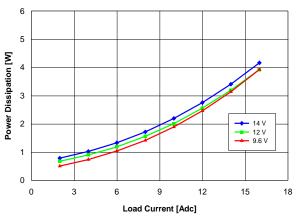


Fig. 2.0V.3: Power loss vs. load current and input voltage for Vout = 2.0V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

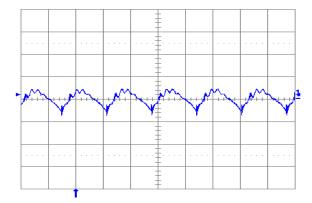


Fig. 2.0V.5: Output voltage ripple (20mV/div.) at full rated load current into a resistive load with external capacitance 100μF ceramic + 1μF ceramic and Vin = 12V for Vout = 2.0V. Time scale: 2μs/div.

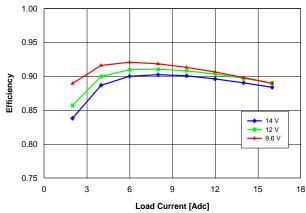


Fig. 2.0V.2: Efficiency vs. load current and input voltage for Vout = 2.0V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

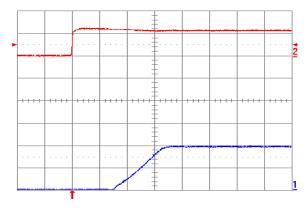


Fig. 2.0V.4: Turn-on transient for Vout = 2.0V with application of Vin at full rated load current (resistive) and 100µF external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale: 2ms/div.

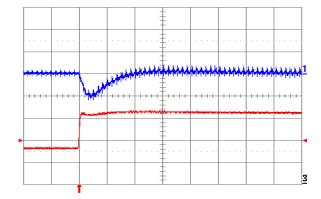


Fig. 2.0V.6: Output voltage response for Vout = 2.0V to positive load current step change from 8A to 16A with slew rate of 5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.



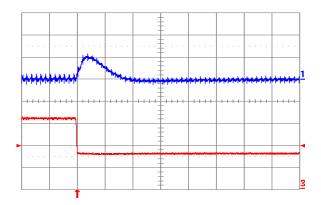


Fig. 2.0V.7: Output voltage response for Vout = 2.0V to negative load current step change from 16A to 8A with slew rate of -5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

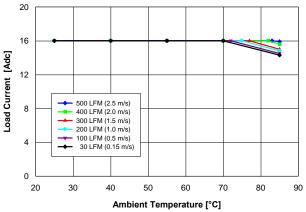


Fig. 1.8V.1: Available load current vs. ambient temperature and airflow rates for Vout = 1.8V converter mounted vertically with Vin = 12V, and maximum MOSFET temperature ≤ 120°C.

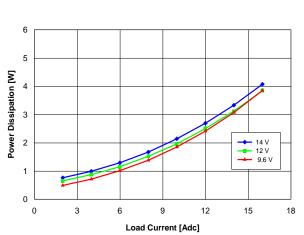


Fig. 1.8V.3: Power loss vs. load current and input voltage for Vout = 1.8V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

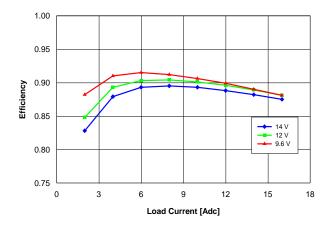


Fig. 1.8V.2: Efficiency vs. load current and input voltage for Vout = 1.8V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

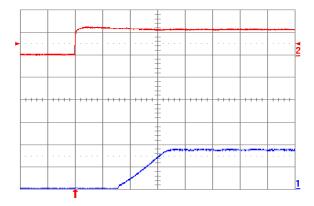


Fig. 1.8V.4: Turn-on transient for Vout = 1.8V with application of Vin at full rated load current (resistive) and 100µF external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale:



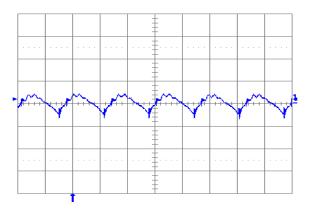


Fig. 1.8V.5: Output voltage ripple (20mV/div.) at full rated load current into a resistive load with external capacitance 100μF ceramic + 1μF ceramic and Vin = 12V for Vout = 1.8V.

Time scale: 2μs/div.

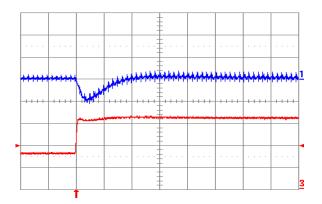


Fig. 1.8V.6: Output voltage response for Vout = 1.8V to positive load current step change from 8A to 16A with slew rate of 5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

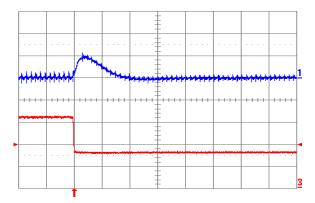


Fig. 1.8V.7: Output voltage response for Vout = 1.8V to negative load current step change from 16A to 8A with slew rate of -5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

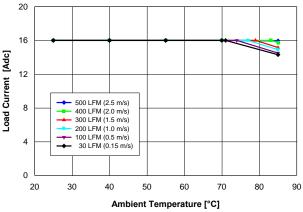


Fig. 1.5V.1: Available load current vs. ambient temperature and airflow rates for Vout = 1.5V converter mounted vertically with Vin = 12V, air flowing and maximum MOSFET temperature ≤ 120°C.

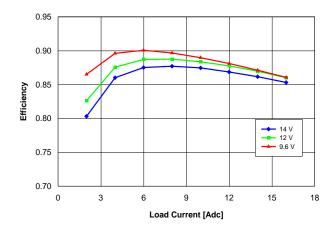


Fig. 1.5V.2: Efficiency vs. load current and input voltage for Vout = 1.5V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.



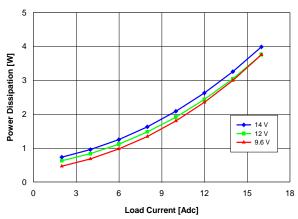


Fig. 1.5V.3: Power loss vs. load current and input voltage for Vout = 1.5V converter mounted vertically with air flowing at a

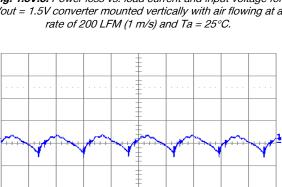


Fig. 1.5V.5: Output voltage ripple (20mV/div.) at full rated load current into a resistive load with external capacitance 100μF ceramic + 1μF ceramic and Vin = 12V for Vout = 1.5V. Time scale: 2µs/div.

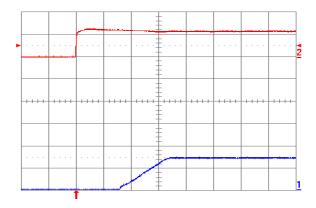


Fig. 1.5V.4: Turn-on transient for Vout = 1.5V with application of Vin at full rated load current (resistive) and 100μF external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale: 2ms/div.

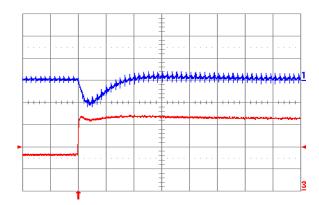


Fig. 1.5V.6: Output voltage response for Vout = 1.5V to positive load current step change from 8A to 16A with slew rate of 5A/µs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

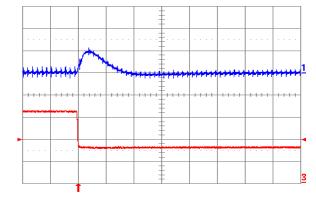


Fig. 1.5V.7: Output voltage response for Vout = 1.5V to negative load current step change from 16A to 8A with slew rate of -5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.



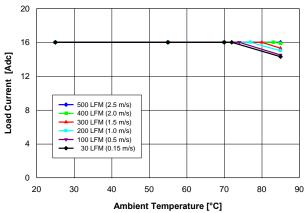


Fig. 1.2V.1: Available load current vs. ambient temperature and airflow rates for Vout = 1.2V converter mounted vertically with Vin = 12V, and maximum MOSFET temperature ≤ 120°C.

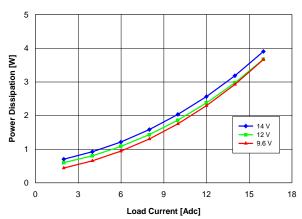


Fig. 1.2V.3: Power loss vs. load current and input voltage for Vout = 1.2V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

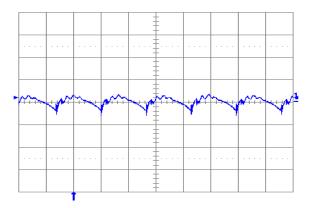


Fig. 1.2V.5: Output voltage ripple (20mV/div.) at full rated load current into a resistive load with external capacitance 100μF ceramic + 1μF ceramic and Vin = 12V for Vout = 1.2V. Time scale: 2μs/div.

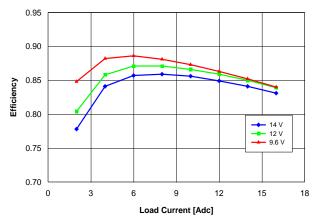


Fig. 1.2V.2: Efficiency vs. load current and input voltage for Vout = 1.2V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

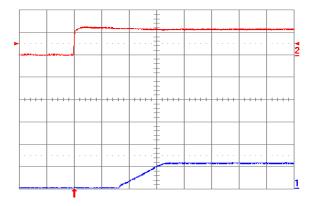


Fig. 1.2V.4: Turn-on transient for Vout = 1.2V with application of Vin at full rated load current (resistive) and 100μF external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale: 2ms/div.

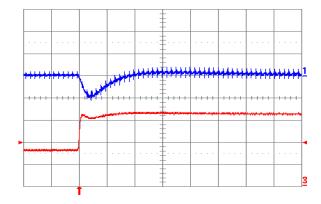


Fig. 1.2V.6: Output voltage response for Vout = 1.2V to positive load current step change from 8A to 16A with slew rate of 5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.



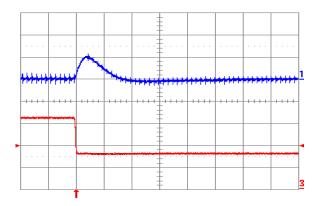


Fig. 1.2V.7: Output voltage response for Vout = 1.2V to negative load current step change from 16A to 8A with slew rate of -5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

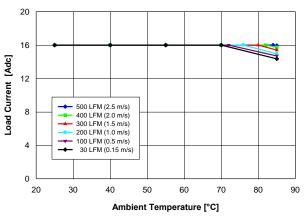


Fig. 1.0V.1: Available load current vs. ambient temperature and airflow rates for Vout = 1.0V converter mounted vertically with Vin = 12V, and maximum MOSFET temperature ≤ 120°C.

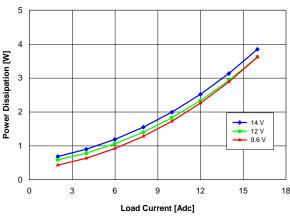


Fig. 1.0V.3: Power loss vs. load current and input voltage for Vout = 1.0V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

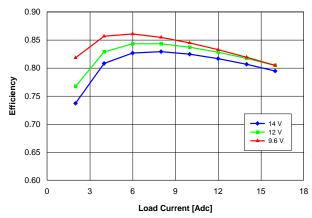


Fig. 1.0V.2: Efficiency vs. load current and input voltage for Vout = 1.0V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

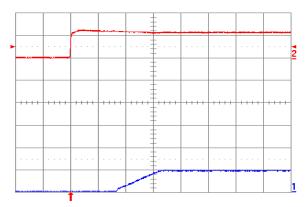


Fig. 1.0V.4: Turn-on transient for Vout = 1.0V with application of Vin at full rated load current (resistive) and 100μF external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale: 2ms/div.



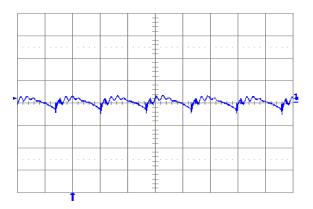


Fig. 1.0V.5: Output voltage ripple (20mV/div.) at full rated load current into a resistive load with external capacitance 100μF ceramic + 1μF ceramic and Vin = 12V for Vout = 1.0V. Time scale: 2μs/div.

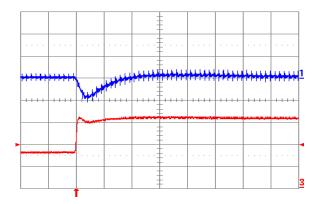


Fig. 1.0V.6: Output voltage response for Vout = 1.0V to positive load current step change from 8A to 16A with slew rate of 5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

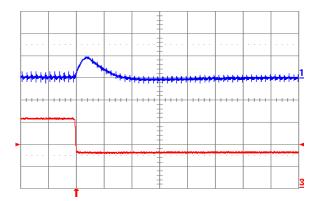


Fig. 1.0V.7: Output voltage response for Vout = 1.0V to negative load current step change from 16A to 8A with slew rate of -5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

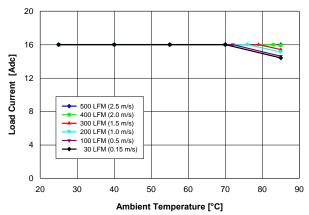


Fig. 0.7525V.1: Available load current vs. ambient temperature and airflow rates for Vout = 1.0V converter mounted vertically with Vin = 12V, and maximum MOSFET temperature ≤ 120°C.

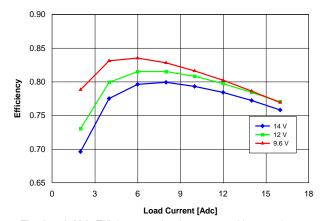


Fig. 0.7525V.2: Efficiency vs. load current and input voltage for Vout = 0.7525V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.



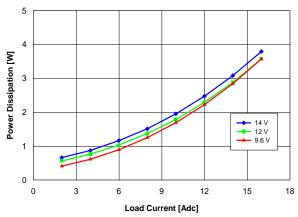


Fig. 0.7525V.3: Power loss vs. load current and input voltage for Vout = 0.7525V converter mounted vertically with air flowing at a rate of 200 LFM (1 m/s) and Ta = 25°C.

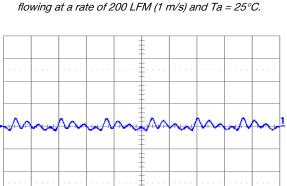


Fig. 0.7525V.5: Output voltage ripple (20mV/div.) at full rated load current into a resistive load with external capacitance 100μF ceramic + 1μF ceramic and Vin = 12V for Vout = 0.7525V. Time scale: 2μs/div.

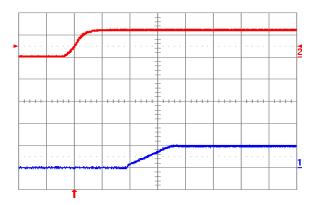


Fig. 0.7525V.4: Turn-on transient for Vout = 0.7525V with application of Vin at full rated load current (resistive) and 100μF external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale: 2ms/div.

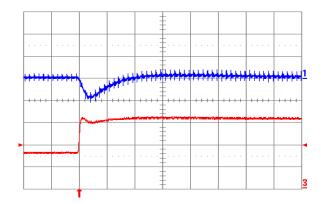


Fig. 0.7525V.6: Output voltage response for Vout = 0.7525V to positive load current step change from 8A to 16A with slew rate of 5A/μs at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co = 100μF ceramic. Time scale: 20μs/div.

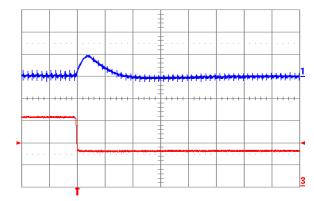
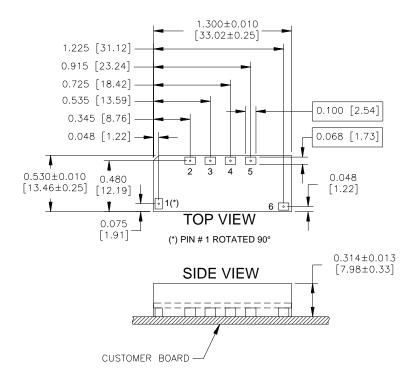


Fig. 0.7525V.7: Output voltage response for Vout = 0.7525V to negative load current step change from 16A to 8A with slew rate of  $5A/\mu s$  at Vin = 12V. Top trace: output voltage (200mV/div.); Bottom trace: load current (5A/div.). Co =  $100\mu F$  ceramic. Time scale:  $20\mu s/div$ .





### **Physical Information**



PAD/PIN CONNECTIONS			
Pad/Pin #	Function		
1	ON/OFF		
2	SENSE		
3	TRIM		
4	Vout		
5	GND		
6	Vin		

#### YS12S Platform Notes

- All dimensions are in inches [mm]
- Connector Material: Copper
- Connector Finish: Gold over Nickel
- Converter Weight: 0.23 oz [6.50 g]
- Converter Height: 0.327" Max., 0.301" Min.
- Recommended Surface-Mount Pads:
   Min. 0.080" X 0.112" [2.03 x 2.84]

YS12S Pinout (Surface Mount)

### **Ordering Information**

Product Series	Input Voltage	Mounting Scheme	Rated Load Current	Enable Logic	RoHS Compatible
YS	12	s	16	- 0	G
Y-Series	9.6 V – 14 V	S ⇒ Surface-Mount	16 A	$0 \Rightarrow$ Standard (Positive Logic)	$\begin{array}{c} \text{No Suffix} \ \Rightarrow \text{RoHS} \\ \text{lead-solder-exempt compliant} \end{array}$
		(0.7525 V to 5.5 V)	D ⇒ Opposite of Standard (Negative Logic)	$\label{eq:G} \begin{split} G \Rightarrow RoHS & \ compliant \ for \ all \\ & \ six \ substances \end{split}$	

The example above describes P/N YS12S16-0G: 9.6V – 14V input, surface mount, 16A at 0.7525V to 5.5V output, standard enable logic, and RoHS compliant for all six substances. Please consult factory regarding availability of a specific version.

### For more information on these products consult: tech.support@psbel.com

**NUCLEAR AND MEDICAL APPLICATIONS** - Products are not designed or intended for use as critical components in life support systems, equipment used in hazardous environments, or nuclear control systems.

**TECHNICAL REVISIONS** - The appearance of products, including safety agency certifications pictured on labels, may change depending on the date manufactured. Specifications are subject to change without notice.

